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Understanding <u>Embedded - FPGAs (Field Programmable Gate Array)</u>

Embedded - FPGAs, or Field Programmable Gate Arrays, are advanced integrated circuits that offer unparalleled flexibility and performance for digital systems. Unlike traditional fixed-function logic devices, FPGAs can be programmed and reprogrammed to execute a wide array of logical operations, enabling customized functionality tailored to specific applications. This reprogrammability allows developers to iterate designs quickly and implement complex functions without the need for custom hardware.

Applications of Embedded - FPGAs

The versatility of Embedded - FPGAs makes them indispensable in numerous fields. In telecommunications.

Details	
Product Status	Active
Number of LABs/CLBs	2880
Number of Logic Elements/Cells	-
Total RAM Bits	-
Number of I/O	174
Number of Gates	48000
Voltage - Supply	3V ~ 3.6V, 4.75V ~ 5.25V
Mounting Type	Surface Mount
Operating Temperature	-55°C ~ 125°C (TJ)
Package / Case	208-BFCQFP with Tie Bar
Supplier Device Package	208-CQFP (75x75)
Purchase URL	https://www.e-xfl.com/product-detail/microchip-technology/a54sx32-1cq208b

Email: info@E-XFL.COM

Address: Room A, 16/F, Full Win Commercial Centre, 573 Nathan Road, Mongkok, Hong Kong

The R-cell contains a flip-flop featuring asynchronous clear, asynchronous preset, and clock enable (using the S0 and S1 lines) control signals (Figure 1-2). The R-cell registers feature programmable clock polarity selectable on a register-by-register basis. This provides additional

flexibility while allowing mapping of synthesized functions into the SX FPGA. The clock source for the R-cell can be chosen from either the hardwired clock or the routed clock.

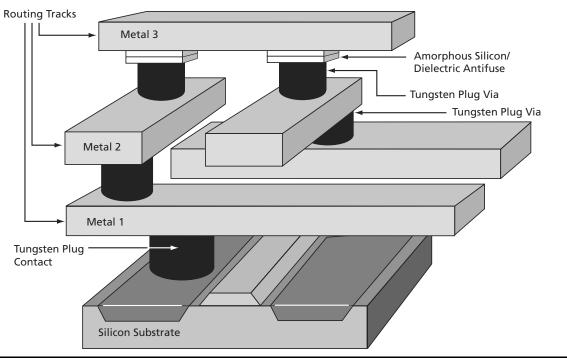


Figure 1-1 • SX Family Interconnect Elements

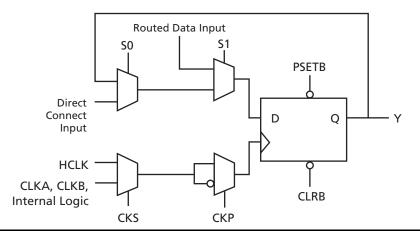


Figure 1-2 • R-Cell

The C-cell implements a range of combinatorial functions up to 5-inputs (Figure 1-3 on page 1-3). Inclusion of the DB input and its associated inverter function dramatically increases the number of combinatorial functions that can be implemented in a single module from 800 options in previous architectures to more than 4,000 in the SX architecture. An example of the improved flexibility

enabled by the inversion capability is the ability to integrate a 3-input exclusive-OR function into a single C-cell. This facilitates construction of 9-bit parity-tree functions with 2 ns propagation delays. At the same time, the C-cell structure is extremely synthesis friendly, simplifying the overall design and reducing synthesis time.

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Routing Resources

Clusters and SuperClusters can be connected through the use of two innovative local routing resources called *FastConnect* and *DirectConnect*, which enable extremely fast and predictable interconnection of modules within clusters and SuperClusters (Figure 1-5 and Figure 1-6). This routing architecture also dramatically reduces the number of antifuses required to complete a circuit, ensuring the highest possible performance.

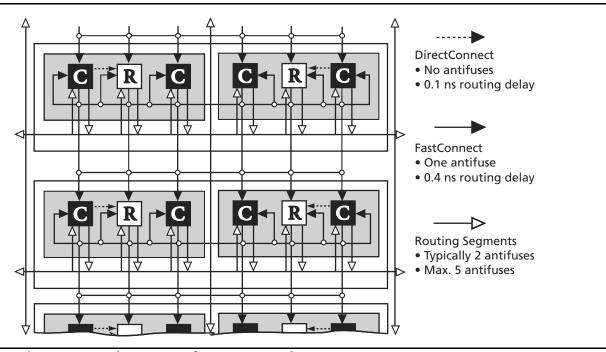


Figure 1-5 • DirectConnect and FastConnect for Type 1 SuperClusters

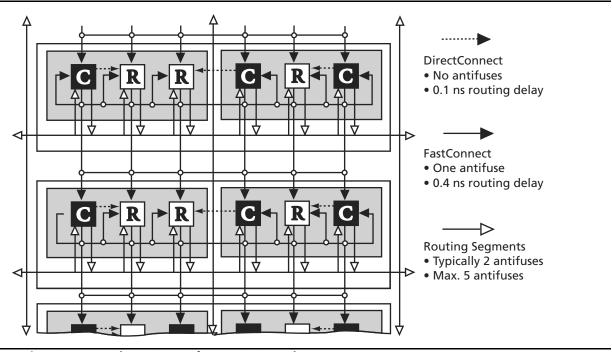


Figure 1-6 • DirectConnect and FastConnect for Type 2 SuperClusters

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Boundary Scan Testing (BST)

All SX devices are IEEE 1149.1 compliant. SX devices offer superior diagnostic and testing capabilities by providing Boundary Scan Testing (BST) and probing capabilities. These functions are controlled through the special test pins in conjunction with the program fuse. The functionality of each pin is described in Table 1-2. In the dedicated test mode, TCK, TDI, and TDO are dedicated pins and cannot be used as regular I/Os. In flexible mode, TMS should be set HIGH through a pull-up resistor of $10~\mathrm{k}\Omega$. TMS can be pulled LOW to initiate the test sequence.

The program fuse determines whether the device is in dedicated or flexible mode. The default (fuse not blown) is flexible mode.

Table 1-2 ● **Boundary Scan Pin Functionality**

Program Fuse Blown (Dedicated Test Mode)	Program Fuse Not Blown (Flexible Mode)			
TCK, TDI, TDO are dedicated BST pins.	TCK, TDI, TDO are flexible and may be used as I/Os.			
No need for pull-up resistor for TMS	Use a pull-up resistor of 10 k Ω on TMS.			

Dedicated Test Mode

In Dedicated mode, all JTAG pins are reserved for BST; designers cannot use them as regular I/Os. An internal pull-up resistor is automatically enabled on both TMS and TDI pins, and the TMS pin will function as defined in the IEEE 1149.1 (JTAG) specification.

To select Dedicated mode, users need to reserve the JTAG pins in Actel's Designer software by checking the "Reserve JTAG" box in "Device Selection Wizard" (Figure 1-7). JTAG pins comply with LVTTL/TTL I/O specification regardless of whether they are used as a user I/O or a JTAG I/O. Refer to the Table 1-5 on page 1-8 for detailed specifications.

Figure 1-7 • Device Selection Wizard

Development Tool Support

The SX family of FPGAs is fully supported by both the Actel Libero® Integrated Design Environment (IDE) and Designer FPGA Development software. Actel Libero IDE is a design management environment, seamlessly integrating design tools while guiding the user through the design flow, managing all design and log files, and passing necessary design data among tools. Libero IDE allows users to integrate both schematic and HDL synthesis into a single flow and verify the entire design in a single environment. Libero IDE includes Synplify® for Actel from Synplicity[®], ViewDraw[®] for Actel from Mentor Graphics[®], ModelSim[®] HDL Simulator from Mentor Graphics, WaveFormer Lite™ SynaptiCAD™, and Designer software from Actel. Refer to the Libero IDE flow diagram (located on the Actel website) for more information.

Actel Designer software is a place-and-route tool and provides a comprehensive suite of backend support tools for FPGA development. The Designer software includes timing-driven place-and-route, and a world-class integrated static timing analyzer and constraints editor. With the Designer software, a user can select and lock package pins while only minimally impacting the results of place-and-route. Additionally, the back-annotation flow is compatible with all the major simulators, and the simulation results can be cross-probed with Silicon Explorer II, Actel integrated verification and logic analysis tool. Another tool included in the Designer software is the SmartGen core generator, which easily creates popular and commonly used logic functions for implementation into your schematic or HDL design. Actel Designer software is compatible with the most popular FPGA design entry and verification tools from companies such as Mentor Graphics, Synplicity, Synopsys[®], and Cadence® Design Systems. The Designer software is available for both the Windows® and UNIX® operating systems.

Probe Circuit Control Pins

The Silicon Explorer II tool uses the boundary scan ports (TDI, TCK, TMS, and TDO) to select the desired nets for verification. The selected internal nets are assigned to the PRA/PRB pins for observation. Figure 1-8 on page 1-7 illustrates the interconnection between Silicon Explorer II and the FPGA to perform in-circuit verification.

Design Considerations

The TDI, TCK, TDO, PRA, and PRB pins should not be used as input or bidirectional ports. Because these pins are active during probing, critical signals input through these pins are not available while probing. In addition, the Security Fuse should not be programmed because doing so disables the Probe Circuitry.

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Table 1-4 • Recommended Operating Conditions

Parameter	Commercial	Industrial	Military	Units
Temperature Range*	0 to + 70	-40 to + 85	-55 to +125	°C
3.3 V Power Supply Tolerance	±10	±10	±10	%V _{CC}
5.0 V Power Supply Tolerance	±5	±10	±10	%V _{CC}

Note: *Ambient temperature (T_A) is used for commercial and industrial; case temperature (T_C) is used for military.

Table 1-5 ● **Electrical Specifications**

		Comm	Commercial		Industrial		
Symbol	Parameter	Min.	Мах.	Min.	Max.	Units	
V _{OH}	(I _{OH} = -20 μA) (CMOS)	(V _{CCI} – 0.1)	V _{CCI}	(V _{CCI} – 0.1)	V _{CCI}	V	
	$(I_{OH} = -8 \text{ mA}) \text{ (TTL)}$	2.4	V_{CCI}				
	$(I_{OH} = -6 \text{ mA}) \text{ (TTL)}$			2.4	V_{CCI}		
V _{OL}	(I _{OL} = 20 μA) (CMOS)		0.10			V	
	(I _{OL} = 12 mA) (TTL)		0.50				
	$(I_{OL} = 8 \text{ mA}) \text{ (TTL)}$				0.50		
V_{IL}			8.0		0.8	V	
V_{IH}		2.0		2.0		V	
t _R , t _F	Input Transition Time t _R , t _F		50		50	ns	
C _{IO}	C _{IO} I/O Capacitance		10		10	pF	
I _{CC}	Standby Current, I _{CC}		4.0		4.0	mA	
$I_{CC(D)}$	I _{CC(D)} I _{Dynamic} V _{CC} Supply Current	See '	See "Evaluating Power in SX Devices" on page 1-16.				

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PCI Compliance for the SX Family

The SX family supports 3.3 V and 5.0 V PCI and is compliant with the PCI Local Bus Specification Rev. 2.1.

Table 1-6 • A54SX16P DC Specifications (5.0 V PCI Operation)

Symbol	Parameter	Condition	Min.	Max.	Units
V_{CCA}	Supply Voltage for Array		3.0	3.6	V
V_{CCR}	Supply Voltage required for Internal Biasing		4.75	5.25	V
V_{CCI}	Supply Voltage for I/Os		4.75	5.25	V
V _{IH}	Input High Voltage ¹		2.0	$V_{CC} + 0.5$	V
V _{IL}	Input Low Voltage ¹		-0.5	0.8	V
I _{IH}	Input High Leakage Current	V _{IN} = 2.7		70	μΑ
I _{IL}	Input Low Leakage Current	V _{IN} = 0.5		-70	μΑ
V _{OH}	Output High Voltage	$I_{OUT} = -2 \text{ mA}$	2.4		V
V _{OL}	Output Low Voltage ²	I _{OUT} = 3 mA, 6 mA		0.55	V
C _{IN}	Input Pin Capacitance ³			10	рF
C _{CLK}	CLK Pin Capacitance		5	12	рF
C _{IDSEL}	IDSEL Pin Capacitance ⁴			8	pF

Notes:

- 1. Input leakage currents include hi-Z output leakage for all bidirectional buffers with tristate outputs.
- 2. Signals without pull-up resistors must have 3 mA low output current. Signals requiring pull-up must have 6 mA; the latter include, FRAME#, IRDY#, TRDY#, DEVSEL#, STOP#, SERR#, PERR#, LOCK#, and, when used, AD[63::32], C/BE[7::4]#, PAR64, REQ64#, and ACK64#.
- 3. Absolute maximum pin capacitance for a PCI input is 10 pF (except for CLK).
- 4. Lower capacitance on this input-only pin allows for non-resistive coupling to AD[xx].

v3.2 1-9

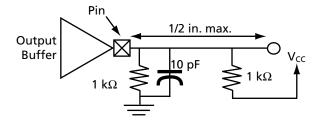
A54SX16P AC Specifications for (PCI Operation)

Table 1-7 • A54SX16P AC Specifications for (PCI Operation)

Symbol	Parameter	Condition	Min.	Max.	Units
I _{OH(AC)}	Switching Current High	$0 < V_{OUT} \le 1.4^{1}$	-44		mA
		$1.4 \le V_{OUT} < 2.4^{1, 2}$	-44 + (V _{OUT} - 1.4)/0.024		mA
		$3.1 < V_{OUT} < V_{CC}^{1, 3}$		EQ 1-1 on page 1-11	
	(Test Point)	$V_{OUT} = 3.1^3$		-142	mA
I _{OL(AC)}	Switching Current High	$V_{OUT} \ge 2.2^1$	95		mA
		$2.2 > V_{OUT} > 0.55^{1}$	V _{OUT} /0.023		
		$0.71 > V_{OUT} > 0^{1, 3}$		EQ 1-2 on page 1-11	mA
	(Test Point)	$V_{OUT} = 0.71^3$		206	mA
I _{CL}	Low Clamp Current	$-5 < V_{IN} \le -1$	-25 + (V _{IN} + 1)/0.015		mA
slew _R	Output Rise Slew Rate	0.4 V to 2.4 V load ⁴	1	5	V/ns
slew _F	Output Fall Slew Rate	2.4 V to 0.4 V load ⁴	1	5	V/ns

Notes:

- 1. Refer to the V/I curves in Figure 1-9 on page 1-11. Switching current characteristics for REQ# and GNT# are permitted to be one half of that specified here; i.e., half-size output drivers may be used on these signals. This specification does not apply to CLK and RST#, which are system outputs. "Switching Current High" specifications are not relevant to SERR#, INTA#, INTB#, INTC#, and INTD#, which are open drain outputs.
- 2. Note that this segment of the minimum current curve is drawn from the AC drive point directly to the DC drive point rather than toward the voltage rail (as is done in the pull-down curve). This difference is intended to allow for an optional N-channel pull-up.
- 3. Maximum current requirements must be met as drivers pull beyond the last step voltage. Equations defining these maximums (A and B) are provided with the respective diagrams in Figure 1-9 on page 1-11. The equation defined maxima should be met by design. In order to facilitate component testing, a maximum current test point is defined for each side of the output driver.
- 4. This parameter is to be interpreted as the cumulative edge rate across the specified range, rather than the instantaneous rate at any point within the transition range. The specified load (diagram below) is optional; i.e., the designer may elect to meet this parameter with an unloaded output per revision 2.0 of the PCI Local Bus Specification. However, adherence to both maximum and minimum parameters is now required (the maximum is no longer simply a guideline). Since adherence to the maximum slew rate was not required prior to revision 2.1 of the specification, there may be components in the market for some time that have faster edge rates; therefore, motherboard designers must bear in mind that rise and fall times faster than this specification could occur, and should ensure that signal integrity modeling accounts for this. Rise slew rate does not apply to open drain outputs.



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A54SX16P DC Specifications (3.3 V PCI Operation)

Table 1-8 • A54SX16P DC Specifications (3.3 V PCI Operation)

Symbol	Parameter	Condition	Min.	Max.	Units
V_{CCA}	Supply Voltage for Array		3.0	3.6	V
V_{CCR}	Supply Voltage required for Internal Biasing		3.0	3.6	V
V_{CCI}	Supply Voltage for I/Os		3.0	3.6	V
V_{IH}	Input High Voltage		0.5V _{CC}	$V_{CC} + 0.5$	V
V_{IL}	Input Low Voltage		-0.5	0.3V _{CC}	V
I _{IPU}	Input Pull-up Voltage ¹		0.7V _{CC}		V
I _{IL}	Input Leakage Current ²	$0 < V_{IN} < V_{CC}$		±10	μΑ
V_{OH}	Output High Voltage	I _{OUT} = -500 μA	0.9V _{CC}		V
V_{OL}	Output Low Voltage	I _{OUT} = 1500 μA		0.1V _{CC}	V
C _{IN}	Input Pin Capacitance ³			10	pF
C _{CLK}	CLK Pin Capacitance		5	12	pF
C _{IDSEL}	IDSEL Pin Capacitance ⁴			8	pF

Notes:

- 1. This specification should be guaranteed by design. It is the minimum voltage to which pull-up resistors are calculated to pull a floated network. Applications sensitive to static power utilization should assure that the input buffer is conducting minimum current at this input voltage.
- 2. Input leakage currents include hi-Z output leakage for all bidirectional buffers with tristate outputs.
- 3. Absolute maximum pin capacitance for a PCI input is 10 pF (except for CLK).
- 4. Lower capacitance on this input-only pin allows for non-resistive coupling to AD[xx].

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Evaluating Power in SX Devices

A critical element of system reliability is the ability of electronic devices to safely dissipate the heat generated during operation. The thermal characteristics of a circuit depend on the device and package used, the operating temperature, the operating current, and the system's ability to dissipate heat.

You should complete a power evaluation early in the design process to help identify potential heat-related problems in the system and to prevent the system from exceeding the device's maximum allowed junction temperature.

The actual power dissipated by most applications is significantly lower than the power the package can dissipate. However, a thermal analysis should be performed for all projects. To perform a power evaluation, follow these steps:

- Estimate the power consumption of the application.
- Calculate the maximum power allowed for the device and package.
- 3. Compare the estimated power and maximum power values.

Estimating Power Consumption

The total power dissipation for the SX family is the sum of the DC power dissipation and the AC power dissipation. Use EQ 1-5 to calculate the estimated power consumption of your application.

$$P_{Total} = P_{DC} + P_{AC}$$

EQ 1-5

n

DC Power Dissipation

The power due to standby current is typically a small component of the overall power. The Standby power is shown in Table 1-12 for commercial, worst-case conditions (70°C).

Table 1-12 • Standby Power

I _{CC}	V _{CC}	Power
4 mA	3.6 V	14.4 mW

The DC power dissipation is defined in EQ 1-6.

$$\begin{split} P_{DC} &= (I_{standby}) \times V_{CCA} + (I_{standby}) \times V_{CCR} + \\ (I_{standby}) \times V_{CCI} + xV_{OL} \times I_{OL} + y(V_{CCI} - V_{OH}) \times V_{OH} \end{split}$$

EQ 1-6

AC Power Dissipation

The power dissipation of the SX Family is usually dominated by the dynamic power dissipation. Dynamic power dissipation is a function of frequency, equivalent capacitance, and power supply voltage. The AC power dissipation is defined in EQ 1-7 and EQ 1-8.

EQ 1-7

$$\begin{split} P_{AC} &= V_{CCA}^2 \times [(m \times C_{EQM} \times f_m)_{Module} + \\ (n \times C_{EQI} \times f_n)_{Input \ Buffer} + (p \times (C_{EQO} + C_L) \times f_p)_{Output \ Buffer} + \\ (0.5 \times (q_1 \times C_{EQCR} \times f_{q_1}) + (r_1 \times f_{q_1}))_{RCLKA} + \\ (0.5 \times (q_2 \times CEQCR \times f_{q_2}) + (r_2 \times f_{q_2}))_{RCLKB} + \\ (0.5 \times (s_1 \times C_{EOHV} \times f_{s_1}) + (C_{EOHF} \times f_{s_1}))_{HCLK}] \end{split}$$

EQ 1-8

Definition of Terms Used in Formula

 $m = Number of logic modules switching at <math>f_m$

Number of input buffers switching at f_n

p = Number of output buffers switching at f_p

q₁ = Number of clock loads on the first routed array clock

q₂ = Number of clock loads on the second routed array clock

x = Number of I/Os at logic low

y = Number of I/Os at logic high

r₁ = Fixed capacitance due to first routed array clock

r₂ = Fixed capacitance due to second routed array clock

s₁ = Number of clock loads on the dedicated array

C_{EOM} = Equivalent capacitance of logic modules in pF

C_{EQI} = Equivalent capacitance of input buffers in pF

C_{EOO} = Equivalent capacitance of output buffers in pF

 C_{EQCR} = Equivalent capacitance of routed array clock in pF

C_{EQHV} = Variable capacitance of dedicated array clock

C_{EOHF} = Fixed capacitance of dedicated array clock

C_I = Output lead capacitance in pF

f_m = Average logic module switching rate in MHz

f_n = Average input buffer switching rate in MHz

f_p = Average output buffer switching rate in MHz

 f_{q1} = Average first routed array clock rate in MHz

f_{q2} = Average second routed array clock rate in MHz

f_{s1} = Average dedicated array clock rate in MHz

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A54SX16 Timing Characteristics

Table 1-18 • A54SX16 Timing Characteristics (Worst-Case Commercial Conditions, V_{CCR} = 4.75 V, V_{CCA}, V_{CCI} = 3.0 V, T_J = 70°C)

	(Norse case commercial conditions, t		Speed		Speed	'-1' \$	Speed	'Std'	Speed	
Parameter	Description	Min.	Max.	Min.	Max.	Min.	Max.	Min.	Max.	Units
C-Cell Propa	agation Delays ¹									
t _{PD}	Internal Array Module		0.6		0.7		8.0		0.9	ns
Predicted R	outing Delays ²									
t _{DC}	FO = 1 Routing Delay, Direct Connect		0.1		0.1		0.1		0.1	ns
t _{FC}	FO = 1 Routing Delay, Fast Connect		0.3		0.4		0.4		0.5	ns
t _{RD1}	FO = 1 Routing Delay		0.3		0.4		0.4		0.5	ns
t _{RD2}	FO = 2 Routing Delay		0.6		0.7		8.0		0.9	ns
t _{RD3}	FO = 3 Routing Delay		8.0		0.9		1.0		1.2	ns
t _{RD4}	FO = 4 Routing Delay		1.0		1.2		1.4		1.6	ns
t _{RD8}	FO = 8 Routing Delay		1.9		2.2		2.5		2.9	ns
t _{RD12}	FO = 12 Routing Delay		2.8		3.2		3.7		4.3	ns
R-Cell Timir	ıg									
t _{RCO}	Sequential Clock-to-Q		0.8		1.1		1.2		1.4	ns
t _{CLR}	Asynchronous Clear-to-Q		0.5		0.6		0.7		8.0	ns
t _{PRESET}	Asynchronous Preset-to-Q		0.7		8.0		0.9		1.0	ns
t _{SUD}	Flip-Flop Data Input Set-Up	0.5		0.5		0.7		8.0		ns
t _{HD}	Flip-Flop Data Input Hold	0.0		0.0		0.0		0.0		ns
t _{WASYN}	Asynchronous Pulse Width	1.4		1.6		1.8		2.1		ns
Input Modu	ile Propagation Delays									
t _{INYH}	Input Data Pad-to-Y HIGH		1.5		1.7		1.9		2.2	ns
t _{INYL}	Input Data Pad-to-Y LOW		1.5		1.7		1.9		2.2	ns
Predicted In	nput Routing Delays ²									
t _{IRD1}	FO = 1 Routing Delay		0.3		0.4		0.4		0.5	ns
t _{IRD2}	FO = 2 Routing Delay		0.6		0.7		8.0		0.9	ns
t _{IRD3}	FO = 3 Routing Delay		8.0		0.9		1.0		1.2	ns
t _{IRD4}	FO = 4 Routing Delay		1.0		1.2		1.4		1.6	ns
t _{IRD8}	FO = 8 Routing Delay		1.9		2.2		2.5		2.9	ns
t _{IRD12}	FO = 12 Routing Delay		2.8		3.2		3.7		4.3	ns

Notes:

- 1. For dual-module macros, use $t_{PD}+t_{RD1}+t_{PDn},\ t_{RCO}+t_{RD1}+t_{PDn},\ or\ t_{PD1}+t_{RD1}+t_{SUD},\ whichever\ is\ appropriate.$
- 2. Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual worst-case performance. Post-route timing is based on actual routing delay measurements performed on the device prior to shipment.
- 3. Delays based on 35 pF loading, except t_{ENZL} and t_{ENZH} . For t_{ENZL} and t_{ENZH} , the loading is 5 pF.

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A54SX32 Timing Characteristics

Table 1-20 • A54SX32 Timing Characteristics (Worst-Case Commercial Conditions, V_{CCR}= 4.75 V, V_{CCA}, V_{CCI} = 3.0 V, T_J = 70°C)

		'-3' \$	Speed	'-2' 9	Speed	'-1' 9	Speed	'Std'	Speed	
Parameter	Description	Min.	Мах.	Min.	Мах.	Min.	Мах.	Min.	Мах.	Units
C-Cell Propa	agation Delays ¹									
t _{PD}	Internal Array Module		0.6		0.7		8.0		0.9	ns
Predicted R	outing Delays ²									
t _{DC}	FO = 1 Routing Delay, Direct Connect		0.1		0.1		0.1		0.1	ns
t _{FC}	FO = 1 Routing Delay, Fast Connect		0.3		0.4		0.4		0.5	ns
t _{RD1}	FO = 1 Routing Delay		0.3		0.4		0.4		0.5	ns
t _{RD2}	FO = 2 Routing Delay		0.7		8.0		0.9		1.0	ns
t _{RD3}	FO = 3 Routing Delay		1.0		1.2		1.4		1.6	ns
t _{RD4}	FO = 4 Routing Delay		1.4		1.6		1.8		2.1	ns
t _{RD8}	FO = 8 Routing Delay		2.7		3.1		3.5		4.1	ns
t _{RD12}	FO = 12 Routing Delay		4.0		4.7		5.3		6.2	ns
R-Cell Timir	ng									
t _{RCO}	Sequential Clock-to-Q		0.8		1.1		1.3		1.4	ns
t _{CLR}	Asynchronous Clear-to-Q		0.5		0.6		0.7		8.0	ns
t _{PRESET}	Asynchronous Preset-to-Q		0.7		8.0		0.9		1.0	ns
t _{SUD}	Flip-Flop Data Input Set-Up	0.5		0.6		0.7		0.8		ns
t _{HD}	Flip-Flop Data Input Hold	0.0		0.0		0.0		0.0		ns
t _{WASYN}	Asynchronous Pulse Width	1.4		1.6		1.8		2.1		ns
Input Modu	ıle Propagation Delays									
t _{INYH}	Input Data Pad-to-Y HIGH		1.5		1.7		1.9		2.2	ns
t _{INYL}	Input Data Pad-to-Y LOW		1.5		1.7		1.9		2.2	ns
Predicted In	nput Routing Delays ²									
t _{IRD1}	FO = 1 Routing Delay		0.3		0.4		0.4		0.5	ns
t _{IRD2}	FO = 2 Routing Delay		0.7		8.0		0.9		1.0	ns
t _{IRD3}	FO = 3 Routing Delay		1.0		1.2		1.4		1.6	ns
t _{IRD4}	FO = 4 Routing Delay		1.4		1.6		1.8		2.1	ns
t _{IRD8}	FO = 8 Routing Delay		2.7		3.1		3.5		4.1	ns
t _{IRD12}	FO = 12 Routing Delay		4.0		4.7		5.3		6.2	ns

Note:

- 1. For dual-module macros, use t_{PD} + t_{RD1} + t_{PDn_r} t_{RCO} + t_{RD1} + t_{PDn_r} or t_{PD1} + t_{RD1} + t_{SUD} , whichever is appropriate.
- 2. Routing delays are for typical designs across worst-case operating conditions. These parameters should be used for estimating device performance. Post-route timing analysis or simulation is required to determine actual worst-case performance. Post-route timing is based on actual routing delay measurements performed on the device prior to shipment.
- 3. Delays based on 35 pF loading, except t_{ENZL} and t_{ENZH} . For t_{ENZL} and t_{ENZH} the loading is 5 pF.

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144-Pin TQFP							
Pin Number	A54SX08 Function	A54SX16P Function	A54SX32 Function				
1	GND	GND	GND				
2	TDI, I/O	TDI, I/O	TDI, I/O				
3	I/O	1/0	I/O				
4	I/O	1/0	I/O				
5	I/O	1/0	I/O				
6	I/O	1/0	1/0				
7	I/O	1/0	I/O				
8	I/O	I/O	1/0				
9	TMS	TMS	TMS				
10	V _{CCI}	V_{CCI}	V _{CCI}				
11	GND	GND	GND				
12	I/O	I/O	1/0				
13	I/O	1/0	I/O				
14	I/O	I/O	1/0				
15	I/O	I/O	1/0				
16	I/O	I/O	I/O				
17	I/O	1/0	1/0				
18	I/O	I/O	1/0				
19	V_{CCR}	V_{CCR}	V_{CCR}				
20	V_{CCA}	V_{CCA}	V_{CCA}				
21	I/O	1/0	I/O				
22	I/O	1/0	I/O				
23	I/O	1/0	I/O				
24	I/O	1/0	I/O				
25	I/O	1/0	I/O				
26	I/O	1/0	I/O				
27	I/O	1/0	I/O				
28	GND	GND	GND				
29	V _{CCI}	V _{CCI}	V _{CCI}				
30	V_{CCA}	V _{CCA}	V _{CCA}				
31	I/O	1/0	I/O				
32	I/O	1/0	I/O				
33	I/O	I/O	1/0				
34	I/O	I/O	1/0				
35	I/O	I/O	I/O				
36	GND	GND	GND				

144-Pin TQFP			
Pin Number	A54SX08 Function	A54SX16P Function	A54SX32 Function
37	I/O	1/0	I/O
38	I/O	1/0	I/O
39	I/O	1/0	I/O
40	I/O	1/0	I/O
41	I/O	1/0	I/O
42	I/O	1/0	I/O
43	I/O	1/0	I/O
44	V _{CCI}	V _{CCI}	V _{CCI}
45	I/O	I/O	I/O
46	I/O	I/O	I/O
47	I/O	I/O	I/O
48	I/O	I/O	I/O
49	I/O	I/O	I/O
50	I/O	1/0	I/O
51	I/O	1/0	I/O
52	I/O	1/0	I/O
53	I/O	1/0	I/O
54	PRB, I/O	PRB, I/O	PRB, I/O
55	I/O	I/O	I/O
56	V_{CCA}	V_{CCA}	V_{CCA}
57	GND	GND	GND
58	V_{CCR}	V_{CCR}	V_{CCR}
59	I/O	I/O	I/O
60	HCLK	HCLK	HCLK
61	I/O	I/O	I/O
62	I/O	1/0	I/O
63	I/O	I/O	I/O
64	I/O	1/0	I/O
65	I/O	I/O	I/O
66	I/O	I/O	I/O
67	I/O	I/O	I/O
68	V _{CCI}	V _{CCI}	V _{CCI}
69	I/O	I/O	I/O
70	I/O	1/0	I/O
71	TDO, I/O	TDO, I/O	TDO, I/O
72	I/O	I/O	I/O
		-	

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176-Pin TQFP

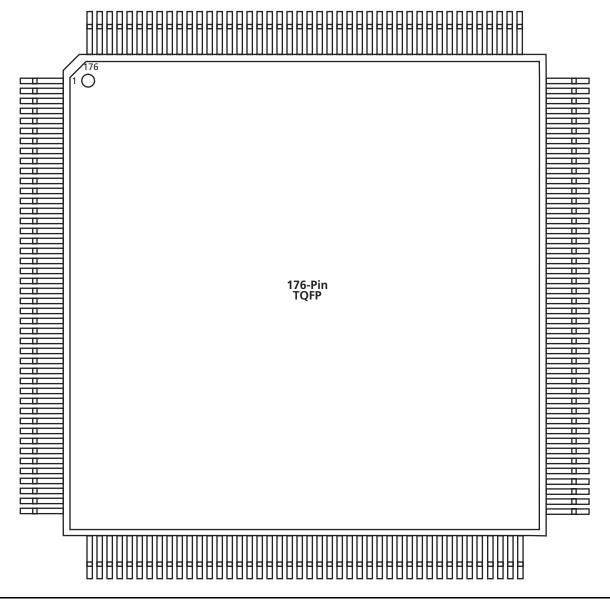


Figure 2-4 • 176-Pin TQFP (Top View)

Note

For Package Manufacturing and Environmental information, visit the Package Resource center at http://www.actel.com/products/rescenter/package/index.html.

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176-Pin TQFP			
Pin Number	A54SX08 Function	A54SX16, A54SX16P Function	A54SX32 Function
69	HCLK	HCLK	HCLK
70	I/O	I/O	I/O
71	I/O	1/0	I/O
72	I/O	I/O	I/O
73	I/O	I/O	I/O
74	I/O	I/O	I/O
75	I/O	I/O	I/O
76	I/O	I/O	I/O
77	I/O	I/O	I/O
78	I/O	I/O	I/O
79	NC	1/0	I/O
80	I/O	1/0	I/O
81	NC	1/0	I/O
82	V _{CCI}	V _{CCI}	V _{CCI}
83	I/O	I/O	I/O
84	I/O	I/O	I/O
85	I/O	I/O	I/O
86	I/O	1/0	I/O
87	TDO, I/O	TDO, I/O	TDO, I/O
88	I/O	1/0	I/O
89	GND	GND	GND
90	NC	1/0	I/O
91	NC	I/O	I/O
92	I/O	I/O	I/O
93	I/O	1/0	I/O
94	I/O	I/O	I/O
95	I/O	I/O	I/O
96	I/O	I/O	I/O
97	I/O	I/O	I/O
98	V_{CCA}	V _{CCA}	V_{CCA}
99	V _{CCI}	V _{CCI}	V _{CCI}
100	I/O	I/O	I/O
101	I/O	I/O	I/O
102	I/O	1/0	I/O

176-Pin TQFP			
Pin Number	A54SX08 Function	A54SX16, A54SX16P Function	A54SX32 Function
103	I/O	1/0	1/0
104	I/O	1/0	I/O
105	I/O	1/0	1/0
106	I/O	1/0	I/O
107	I/O	I/O	1/0
108	GND	GND	GND
109	V_{CCA}	V_{CCA}	V_{CCA}
110	GND	GND	GND
111	I/O	I/O	1/0
112	I/O	1/0	1/0
113	I/O	I/O	1/0
114	I/O	1/0	I/O
115	I/O	1/0	1/0
116	I/O	1/0	I/O
117	I/O	1/0	1/0
118	NC	1/0	I/O
119	I/O	1/0	1/0
120	NC	1/0	I/O
121	NC	1/0	I/O
122	V_{CCA}	V_{CCA}	V_{CCA}
123	GND	GND	GND
124	V _{CCI}	V _{CCI}	V _{CCI}
125	I/O	1/0	I/O
126	I/O	1/0	I/O
127	I/O	1/0	I/O
128	I/O	1/0	1/0
129	I/O	1/0	1/0
130	I/O	1/0	I/O
131	NC	1/0	I/O
132	NC	1/0	I/O
133	GND	GND	GND
134	I/O	I/O	1/0
135	I/O	1/0	I/O
136	1/0	1/0	I/O

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313-Pin PBGA

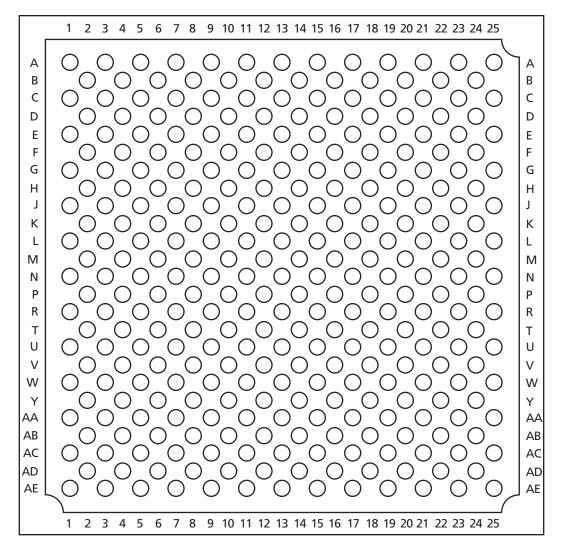


Figure 2-6 • 313-Pin PBGA (Top View)

Note

For Package Manufacturing and Environmental information, visit the Package Resource center at http://www.actel.com/products/rescenter/package/index.html.

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313-Pin PBGA		
Pin	A54SX32	
Number	Function	
H20	I/O	
H22	V_{CCI}	
H24	I/O	
J1	I/O	
J3	1/0	
J5	I/O	
J7	NC	
J9	I/O	
J11	1/0	
J13	CLKA	
J15	I/O	
J17	I/O	
J19	I/O	
J21	GND	
J23	I/O	
J25	I/O	
K2	I/O	
K4	I/O	
K6	I/O	
K8	V _{CCI}	
K10	I/O	
K12	I/O	
K14	I/O	
K16	I/O	
K18	I/O	
K20	V_{CCA}	
K22	I/O	
K24	I/O	
L1	I/O	
L3	I/O	
L5	I/O	
L7	I/O	
L9	I/O	
L11	I/O	
L13	GND	
L15	I/O	
L17	I/O	
L19	I/O	
L21	I/O	
L23	I/O	

313-Pin PBGA		
A54SX32 Function		
I/O		
GND		
GND		
V _{CCI}		
I/O		
V_{CCA}		
V_{CCR}		
I/O		
V _{CCI}		
GND		
GND		
GND		
I/O		
I/O		
I/O		
V_{CCR}		
V_{CCA}		
I/O		
GND		
GND		
I/O		
I/O		
NC		
I/O		

313-Pin PBGA		
Pin Number	A54SX32 Function	
R5	I/O	
R7	I/O	
R9	1/0	
R11	1/0	
R13	GND	
R15	1/0	
R17	1/0	
R19	I/O	
R21	1/0	
R23	1/0	
R25	1/0	
T2	1/0	
T4	I/O	
T6	I/O	
T8	I/O	
T10	1/0	
T12	1/0	
T14	HCLK	
T16	1/0	
T18	1/0	
T20	I/O	
T22	I/O	
T24	I/O	
U1	I/O	
U3	I/O	
U5	V _{CCI}	
U7	I/O	
U9	I/O	
U11	I/O	
U13	1/0	
U15	1/0	
U17	I/O	
U19	1/0	
U21	1/0	
U23	1/0	
U25	I/O	
V2	V_{CCA}	
V4	I/O	
V6	I/O	
V8	I/O	

313-Pin PBGA		
Pin	A54SX32	
Number	Function	
V10	I/O	
V12	I/O	
V14	I/O	
V16	NC	
V18	I/O	
V20	I/O	
V22	V_{CCA}	
V24	V _{CCI}	
W1	I/O	
W3	I/O	
W5	I/O	
W7	NC	
W9	I/O	
W11	I/O	
W13	V _{CCI}	
W15	I/O	
W17	I/O	
W19	I/O	
W21	I/O	
W23	I/O	
W25	I/O	
Y2	I/O	
Y4	I/O	
Y6	I/O	
Y8	I/O	
Y10	I/O	
Y12	I/O	
Y14	I/O	
Y16	1/0	
Y18	1/0	
Y20	NC	
Y22	I/O	
Y24	NC	

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329-Pin PBGA

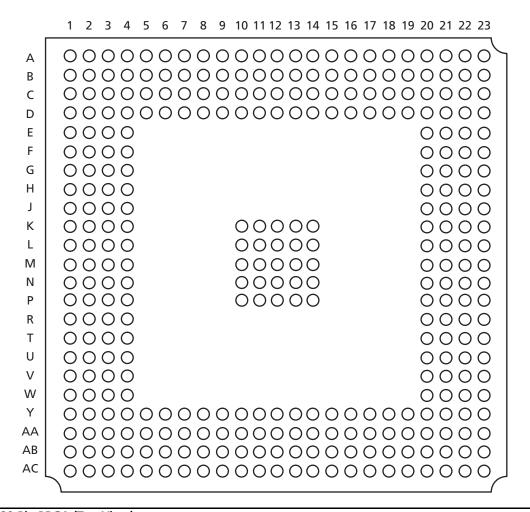


Figure 2-7 • 329-Pin PBGA (Top View)

Note

For Package Manufacturing and Environmental information, visit the Package Resource center at http://www.actel.com/products/rescenter/package/index.html.

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329-Pin PBGA		
Pin Number	A54SX32 Function	
T22	I/O	
T23	I/O	
U1	I/O	
U2	1/0	
U3	V_{CCA}	
U4	1/0	
U20	I/O	
U21	V_{CCA}	
U22	I/O	
U23	I/O	
V1	V _{CCI}	
V2	I/O	
V3	I/O	

329-Pin PBGA		
Pin Number	A54SX32 Function	
V4	I/O	
V20	I/O	
V21	I/O	
V22	I/O	
V23	I/O	
W1	I/O	
W2	I/O	
W3	I/O	
W4	I/O	
W20	I/O	
W21	I/O	
W22	I/O	

329-Pin PBGA		
Pin Number	A54SX32 Function	
W23	NC	
Y1	NC	
Y2	I/O	
Y3	1/0	
Y4	GND	
Y5	I/O	
Y6	1/0	
Y7	1/0	
Y8	1/0	
Y9	1/0	
Y10	1/0	
Y11	I/O	

329-Pin PBGA		
Pin Number	A54SX32 Function	
Y12	V_{CCA}	
Y13	V_{CCR}	
Y14	I/O	
Y15	1/0	
Y16	1/0	
Y17	I/O	
Y18	I/O	
Y19	I/O	
Y20	GND	
Y21	I/O	
Y22	I/O	
Y23	I/O	

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144-Pin FBGA

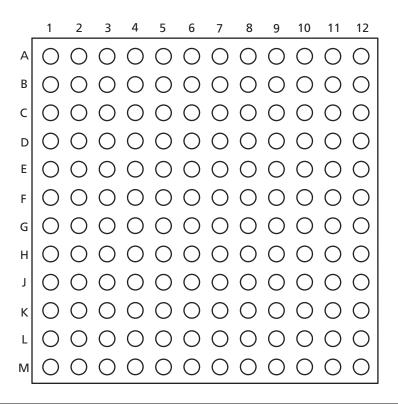


Figure 2-8 • 144-Pin FBGA (Top View)

Note

For Package Manufacturing and Environmental information, visit the Package Resource center at http://www.actel.com/products/rescenter/package/index.html.

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